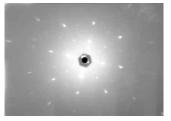
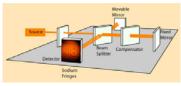


Welcome to

Phys 774: Principles of Spectroscopy



Fall 2007



Lecture 1 Andrei Sirenko, NJIT

Instructor:

Andrei Sirenko

Associate Professor at the Dept. of Physics, NJIT

http://web.njit.edu/~sirenko

476 Tiernan

Office hours: After the classes on We.'s or by appointment

973-596-5342

Class Schedule:

Wednesday 11:30am - 12:55pm | FMH 106 Friday 1:00pm - 2:25pm | FMH 203 SEMICONDUCTOR

Lucent Technologies

Systems

Systems

SEMICONDUCTOR

2000 – 2003

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Plan for today:

- Introduction to the Course
- Introduction to Spectroscopy
- Your PhD projects / motivations
- · Lab tour

Course Elements:

Textbooks:

- J. Michael Hollas, Modern Spectroscopy, 4th edition, Willey, ISBN 0-470-84416-7
- P. Yu and M. Cardona, "Fundamentals of semiconductors" (supplemental textbook)

Lecture Slides

Demonstrations in the Experimental Lab at NJIT

- Raman Scattering in Diamond
- High-Resolution X-ray Diffraction in Silicon wafer
- Transmission in InP-based multilayer device structure
- Micro-beam Photoluminescence in InGaAsP-based waveguide device structure

Grade Components:

- Homework: 10 %
- Research project: 10 %
- Two in-class exams: 15% each;
- Final exam: 50%

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Course Goals:

The major objectives of this course are to integrate theory and practice and to bring together different branches of both Academic studies and Industrial Research through the presentation of critical aspects of modern Spectroscopy. The course will provide a valuable theoretical introduction and an overview of modern topics in spectroscopy, which are of current interest and importance in Semiconductor Industry and Biomedicine. A wide range of techniques is considered, including optical spectroscopy, synchrotron radiation spectroscopy, high-resolution x-ray diffraction, reciprocal space mapping analysis, and FTIR spectroscopy.

To help you with your PhD Project and future jobs

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Outline of the course (continued):

5a.	X-ray	Spectroscopy.

Absorption, Diffraction and Fluorescence

Braggs law; Laue Diffraction

5b. Synchrotron Radiation Facilities, High-resolution X-ray Diffractometers, X-ray Detectors.

5c. HRXRD in Industrial Characterization Labs.

Strain, thickness, and composition measurements in semiconductor device wafers.

Microbeam X-ray spectroscopy, Zone plates, and capillaries. Parameters of Philips Diffractometer

5d. Macromolecular Diffraction. DNA structural analysis. Biomedical applications of X-ray spectroscopy

6a. Neutron Diffraction Spectroscopy

Sources, detectors, diffractometers. Resolution.

Comparison between Neutron and X-ray diffraction spectroscopes 6b. Application of Neutron Diffraction for Solid State Research.

6b. Application of Neutron Diffraction for Solid State Research.

Dispersion of phonons and magnons in Oxide crystals

7 Principles of Modulation Spectroscopy

Spectroscopy of Solids in Electric and Magnetic Field and under Uniaxial and Hydrostatic pressure. Pump-probe Experiments.

8. Overview of NMR and EPR spectroscopy and mass spectrometry for biomedical applications

Outline of the course:

1a. Theory of radiation and Electromagnetic spectrum.

Classification of different parts of Electromagnetic spectrum from radio-frequency waves to hard x-rays and beyond

1b. Radiation sources.

Single wavelength sources. Broadband sources. Lasers, Globars, Synchrotron Radiation Sources.

Characteristics of Radiation: Intensity, Polarization, Coherence Length. CW and pulsed radiation sources

2a. Interaction of Electromagnetic Radiation with Matter.

Dielectric Function Theory. Simple Harmonic Oscillator model. Kramers-Kronig transformation

2b. Linear absorption, Transmission, and Reflection Spectroscopy.

2b. Linear absorption, Transmission, and Reflection Spectr Applications for Solid State and Semiconductors.

2c. Spectrometers and Detectors for Near-IR and Visible range of Electromagnetic spectrum.

Diffraction grating, Single Grating spectrometers, High Resolution Spectrometers, CCD and array detectors. Characteristics of modern JY-Horiba spectrometers and Detectors.

2d. Optical Spectroscopy in Industrial Characterization Lab.

Photoluminescence characterization of Semiconductor Device wavers. Applications of Near-field optical Microscopy (NSOM).

3a. Phonons and Free Electron contribution to the Dielectric Function

IR-active phonons, Electron Plasma Frequency. Magnetic excitations

3.b Far-Infrared spectroscopy.

Michelson interferometers and bolometers. Examples of FT-IR Spectroscopy of High-Tc superconductors and Ferroelectrics.

3c. FT-IR in Industrial characterization Lab for the Process Control analysis.

Thin-films thickness measurements, Interface Quality, Multilayer device structures.

3d. Ellipsometry

3e. Examples of Biomedical Applications of FT-IR spectroscopy

FTIR Spectroscopy in the Clinical Sciences. Probing Drugs distribution in Living Tissue

4a. Nonlinear Spectroscopy

Second harmonic generation, Frequency converters

4b. Raman Scattering Spectroscopy

Raman scattering by electrons and Phonons, Resonant spectroscopy.

4c. Micro-Raman Spectroscopy in Industrial Lab.

Strain and composition measurements in Nitride-based semiconductor wafers

4d. Bio-medical applications of Raman Scattering Spectroscopy.

Whole Cell Studies and Tissue Characterization by Raman Spectroscopy

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Lectures:

- Presentation of the concepts and techniques of Spectroscopy.
- > Demonstrations of Spectroscopy in action.
- Lecture quiz (periodically)
- Lectures are not a substitute for reading the textbook and independent literature search

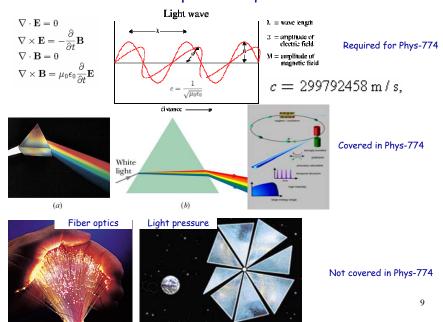
Read ahead; you'll get more from lecture.

> Slides will be posted on the course web.

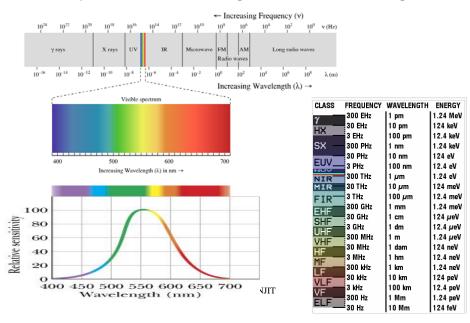
Use these as a study guide/note taking aid

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Scope and Requirements



Spectrum of Electromagnetic Radiation and Light



Intensity of light

$$I = S_{avg} = \left(\frac{energy / time}{area}\right)_{avg} = \left(\frac{power}{area}\right)_{avg}$$

$$I = S_{\text{avg}} = \frac{1}{c \boldsymbol{\mu}_0} \left[E^2 \right]_{\text{avg}} = \frac{1}{c \boldsymbol{\mu}_0} \left[E_m^2 \sin^2(kx - \boldsymbol{\omega} t) \right]_{\text{avg}} \qquad I = \frac{1}{c \boldsymbol{\mu}_0} E_{\text{rms}}^2.$$

$$c = 299792458 \,\mathrm{m/s},$$
 $c = \frac{1}{\sqrt{\mu_0 \epsilon_0}} \,\mathrm{(wave speed)}$

$$c = \frac{1}{\sqrt{\mu_0 \epsilon_0}}$$
 (wave speed)

Point source of light (atom)

Variation of Intensity with Distance



$$I = \frac{P_s}{4\pi r^2}$$

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How can we produce EM waves?

